TOSHIBA PHOTOCOUPLER IRED & PHOTO-TRIAC

TLP3782(S),TLP3783(S)

Office Equipment Home Appliances Triac Drivers Solid State Relays

The TOSHIBA TLP3782(S) and TLP3783(S) consist of an infrared emitting diode optically coupled to a triac-output photocoupler featuring a zero-cross voltage and is housed in a 6-pin DIP package.

The TLP3782(S) and TLP3783(S) offer higher impulse noise immunity than that of the TLP3082(S).

- Peak Off-State Voltage: 800 V (min)
- Trigger LED Current: 10 mA (max) (TLP3782(S))

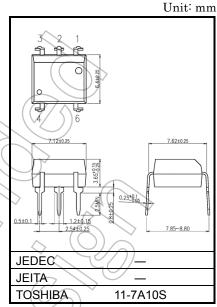
5 mA (max) (TLP3783(S))

- On-State Current: 100 mA (max)
- Isolation Voltage: 5000 Vrms (min)
- UL-recognized: UL 1577, File No.E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349
- VDE-approved : EN 60747-5-5 , EN 62368-1 (Note1)

Note 1: When a VDE approved type is needed, please designate the **Option(D4)**.

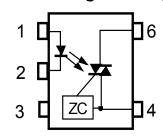
· Construction mechanical rating

	7.62 mm pitch	10.16 mm pitch
	Standard Type	TLPxxxxF type
Creepage Distance Clearance Insulation Thickness	7.0 mm (Min) 7.0 mm (Min) 0.5 mm (Min)	8.0 mm (Min) 8.0 mm (Min) 0.5 mm (Min)



Weight: 0.39g (Typ.)

Pin Configuration (top view)



- 1: Anode
- 2: Cathode
- 3: N.C.
- 4:Terminal 1
- 6:Terminal 2

ZC:Zero-cross Circuit

Start of commercial production 2008-02

Absolute Maximum Ratings (Ta = 25°C)

	Characteristic		Symbol	Rating	Unit
	Forward current		lF	30	mA
	Forward current derating (Ta \geq 53 °C)		ΔI _F /°C	-0.42	mA /°C
	Peak forward current (100 μs pulse, 100 pps)		IFP	4	Α
LED	Reverse voltage		VR	5	V
	Power dissipation		PD	100	mW
	Power dissipation derating (Ta \geq 53°C)		ΔP _D /°C	(-1.4)	mW / °C
	Junction temperature		Ťj	125	°C
	Off-state output terminal voltage		VDRM	800	V
		Ta=25°C		<u>)</u> 100	
	On-state RMS current	Ta=70°C	IT(RMS)	50	mA
tor	On-state current derating (Ta ≥ 25°C)	(-	ΔΙ _Τ / °C	-1.1	mA/°C
Detector	Peak on-state current (100 μs pulse, 120pps)	/ SITP	2 (\bigcirc A	
۵	Peak nonrepetitive surge current (Pw = 10 ms)		ITSM	1.2	A
	Power dissipation	> PD	300	mW	
	Power dissipation derating (Ta ≥ 25 °C)	4(1)	ΔP _D /°C	4.0	mW / °C
	Junction temperature		Tj (115	°C
Ope	rating temperature range		Topr	-40 to 100	°C
Stor	age temperature range	T _{stg}	-55 to 125	°C	
Lead	d soldering temperature (10 s)	T _{sol}	260	°C	
Tota	Il package power dissipation	PŢ	330	mW	
	ll package power dissipation derating ≥ 25°C)	ΔP _T / °C	-4.4	mW / °C	
Isola	ation voltage (AC, 60 s. , R.H. ≤ 60 %)	(Note 1)	BVs	5000	Vrms

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) The devices are considered two-terminal devices: pins 1, 2 and 3 are shorted together, as are pins 4 and 6.

Recommended Operating Conditions

Characteristic		Symbol	Min.	Тур.	Max.	Unit
Supply voltage		VAC	_	_	400	Vac
Forward current	TLP3782	lF	15	20	25	mA
	TLP3783		10	15	20	
Peak on-state current		ITP	_	_	1	Α
Operating temperature		Topr	-25	_	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the devices. Each item also has its own independent guideline document. In developing designs using these products, please confirm the specified characteristics shown in these documents.

Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	VF	I _F = 10 mA	1.05	1.2	1.35	V
LED	Reverse current	IR	V _R = 5 V	_	_	10	μА
	Capacitance	Ст	V = 0 V, f = 1 MHz	-<	10	_	pF
	Peak off-state current	IDRM	V _{DRM} = 800 V	- /	10	1000	nA
	Peak on-state voltage	Vтм	I _{TM} = 100 mA	_ \	1.7	3.0	V
Detector	Holding current	lΗ	_	(7)	0.6	-	mA
Det	Critical rate of rise of off-state voltage	dv/dt	V _{in} = 240 Vrms , Ta = 85 °C (Note 2)	200	2000		V/μs
	Critical rate of rise of commutating voltage	dv/dt(c)	V _{in} = 60 Vrms , I _T = 15 mA (Note 2)	1	2	-	V/μs

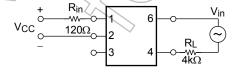
Coupled Electrical Characteristics (Ta = 25°C)

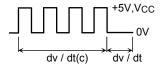
Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit	
Trimment ED aument	TLP3782(S)		V = 2V	-(5	10 mA		
Trigger LED current	TLP3783(S)	lfT	V _T = 3 V	40	$\langle \gamma \rangle$	5	mA	
Inhibit voltage		VIH	IF = Rated IFT			20	٧	
Leakage in inhibited state		Іін	IF = Rated IFT , V _T = Rated V _{DRM}	$(\vee \angle))$	200	600	μΑ	
Turn-on time		ton	VD = $3 \rightarrow 1.5 \text{ V}$, R _L = 20Ω , I _F = Rated I _{FT} x 1.5)	30	100	μS	
Impulse noise durability		VN	tN = 1 μ s, snubber condition (Note 3)	//-	1500	-	٧	

Isolation Characteristics (Ta = 25°C)

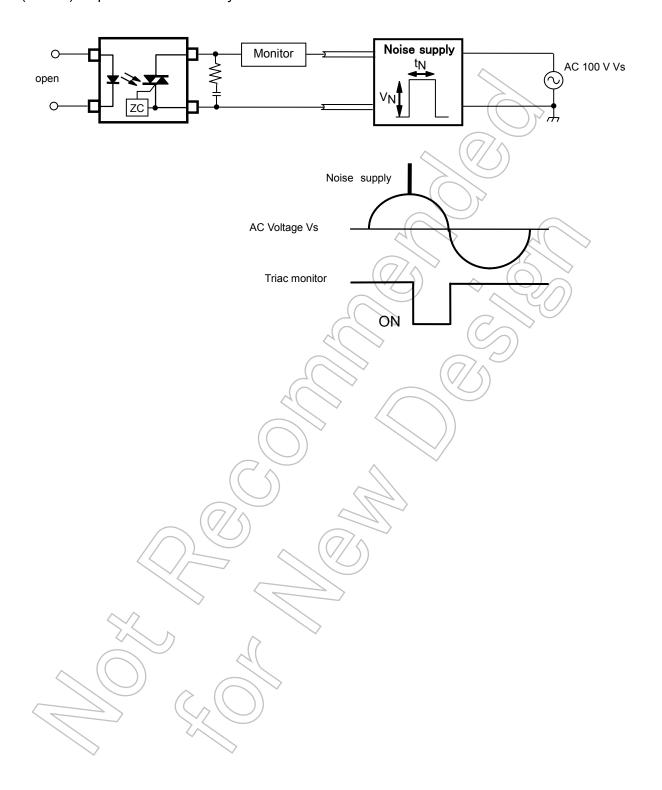
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance (input to output)	Cs	$V_S = 0 V, f = 1 MHz$	_	0.8	_	pF
Isolation resistance	R _s	V _S = 500 V (R.H. ≤ 60 %)	1×10 ¹²	10 ¹⁴	_	Ω
Isolation voltage	BVs	AC , 60 s	5000	_	1	Vrms

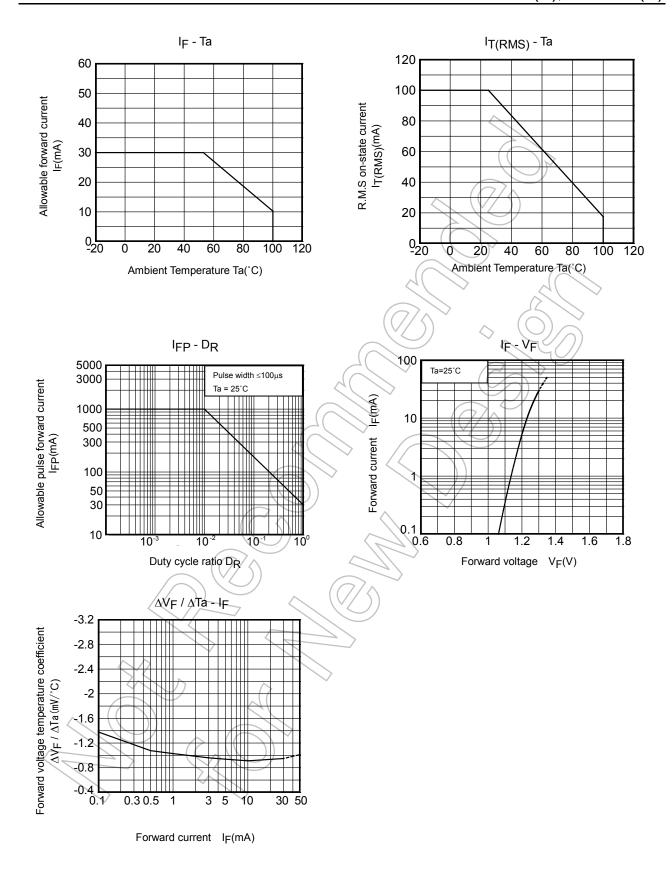
(Note2) dv / dt test circuit



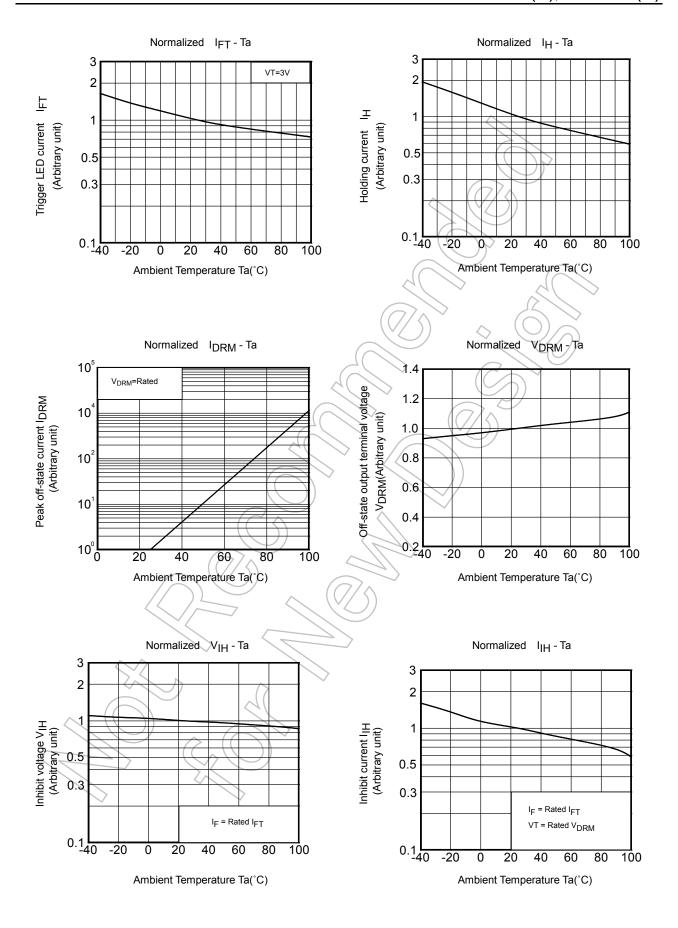


(Note 3): impulse noise durability test circuit





NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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